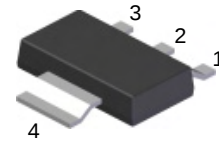


Features

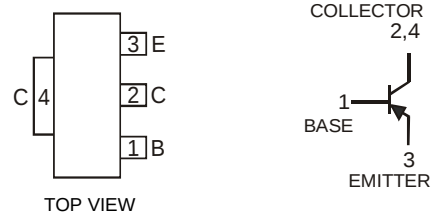
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DCP54)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



SOT-223

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-45	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Current	I _{CM}	-1.5	A
Continuous Collector Current	I _C	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 3)	P _d	1 (Note 3)	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C
Thermal Resistance Junction to Ambient Air @ T _A = 25°C (Note 3)	R _{θJA}	125	°C/W

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-45	—	—	V	I _C = -100μA, I _E = 0A
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-45	—	—	V	I _C = -10mA, I _B = 0A
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5	—	—	V	I _E = -10μA, I _C = 0A
Collector Cut-Off Current	I _{CBO}	—	—	-100 —	nA μA	V _{CB} = -30V, I _E = 0A V _{CB} = - 30V, I _E = 0A, T _A = 150°C
Emitter Cut-Off Current	I _{EBO}	—	—	-10	μA	V _{EB} = -5V, I _C = 0A
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	-0.5	V	I _C = -500mA, I _B = -50mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	—	—	-1.0	V	I _C = -500mA, V _{CE} = -2V
DC Current Gain DCP51-16	h _{FE}	40	—	250	—	I _C = -150mA, V _{CE} = -2V
		25		—		I _C = -500mA, V _{CE} = -2V
		100	—	250		I _C = -150mA, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	—	200	—	MHz	I _C = -50mA, V _{CE} = -5V, f = 100MHz

- Note:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB pad layout as shown on page 4 or on Diodes, Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%

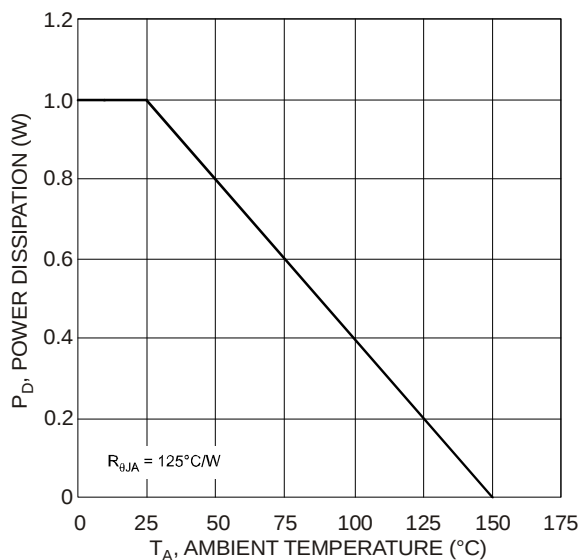


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

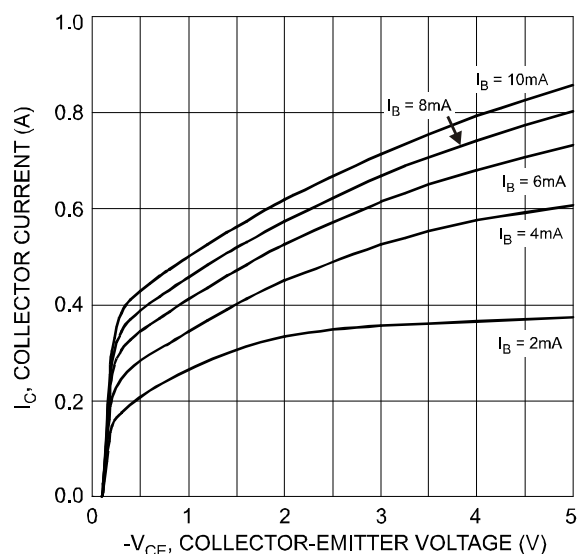


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

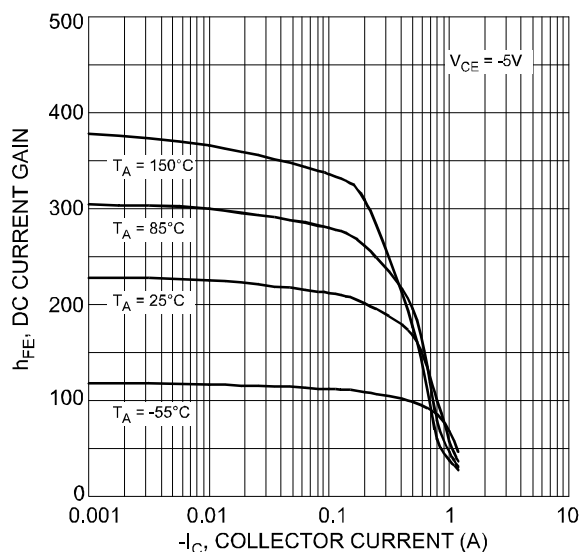


Fig. 3 Typical DC Current Gain vs. Collector Current

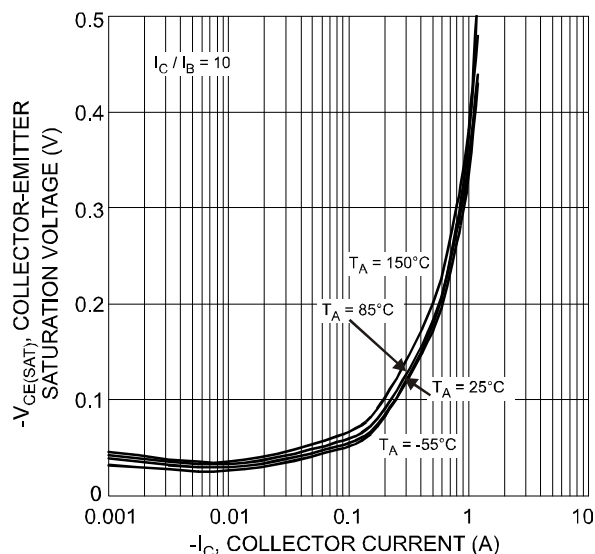


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

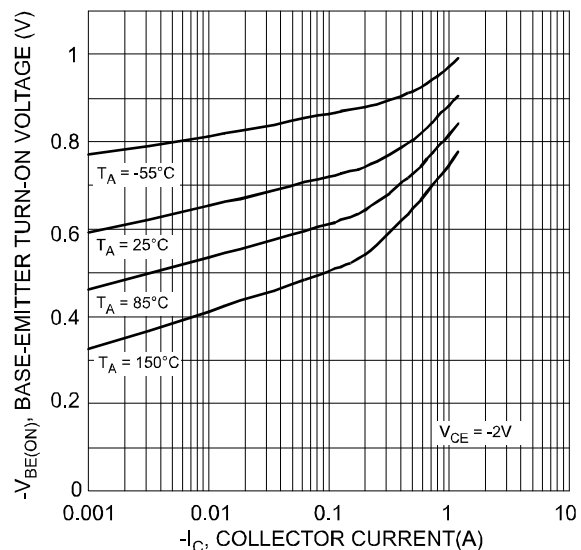


Fig. 5. Typical Base-Emitter Turn-On Voltage vs. Collector Current

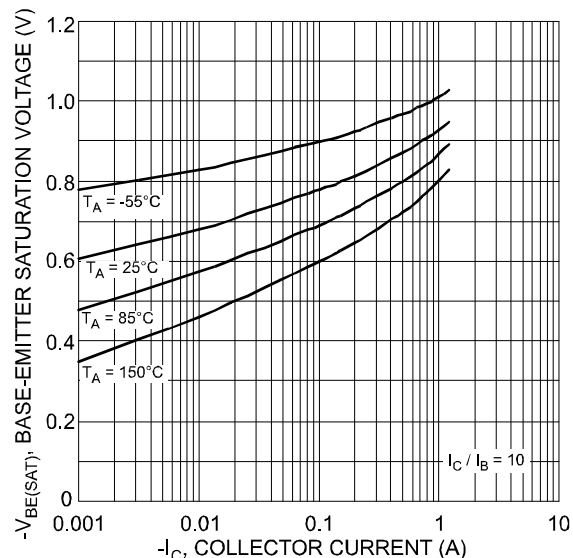
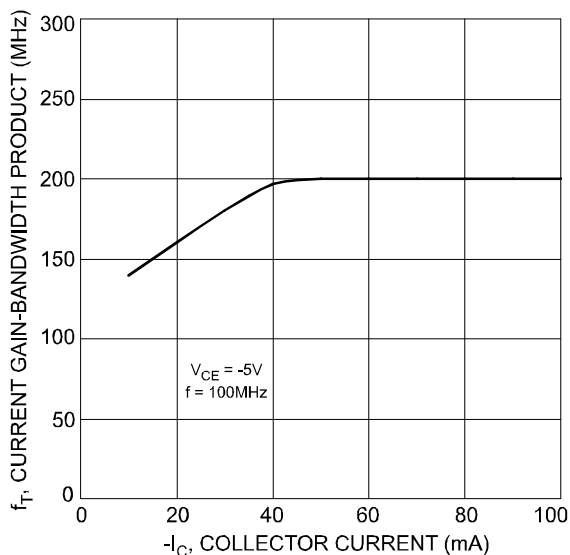
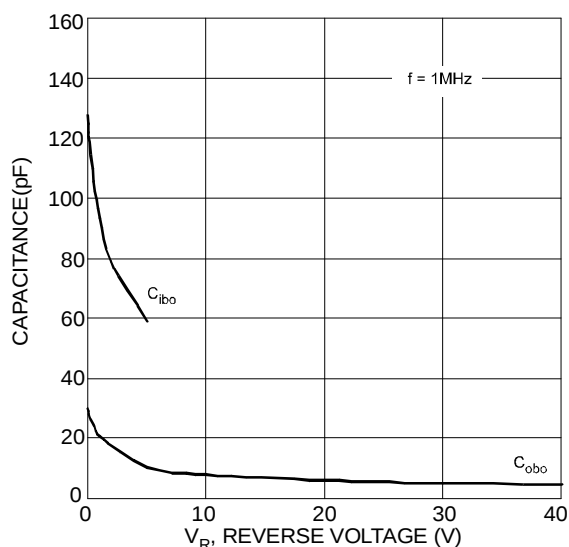
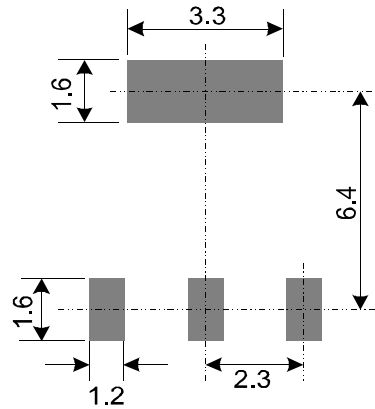


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current



Suggested Pad Layout: (Based on IPC-SM-782)

(Unit:mm)

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.